

80EBU04

 $t_{rr} = 50ns (typ)$

 $I_{F(AV)} = 80Amp$

 $V_R = 400V$

Ultrafast Soft Recovery Diode

Features

- Ultrafast Recovery
- 175°C Operating Junction Temperature
- · Screw Mounting Only
- Lead-Free Plating

Benefits

- Reduced RFI and EMI
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

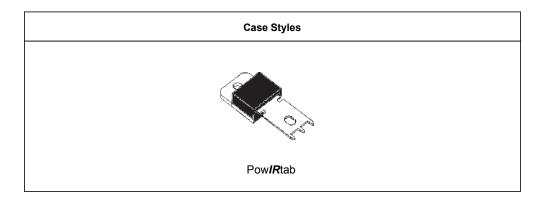
Description/Applications

These diodes are optimized to reduce losses and EMI/ RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

	Parameters	Max	Units
V _R	Cathode to Anode Voltage	400	V
I _{F(AV)}	Continuous Forward Current, T _C = 101°C	80	A
I _{FSM}	Single Pulse Forward Current, T _C = 25°C	800	
I _{FRM} ①	Maximum Repetitive Forward Current	160	
T _J , T _{STG}	Operating Junction and Storage Temperatures	- 55 to 175	°C

① Square Wave, 20kHz



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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	400	-	-	٧	Ι _R = 100μΑ
V _F	Forward Voltage	-	1.1	1.3	٧	I _F = 80A
		-	0.92	1.08	V	I _F = 80A, T _J = 175°C
		-	0.98	1.15	V	I _F = 80A, T _J = 125°C
I _R	Reverse Leakage Current	-	-	50	μA	$V_R = V_R$ Rated
		-	-	2	mA	$T_J = 150$ °C, $V_R = V_R$ Rated
Ст	Junction Capacitance	-	50	-	pF	V _R = 200V
L _S	Series Inductance	-	3.5	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

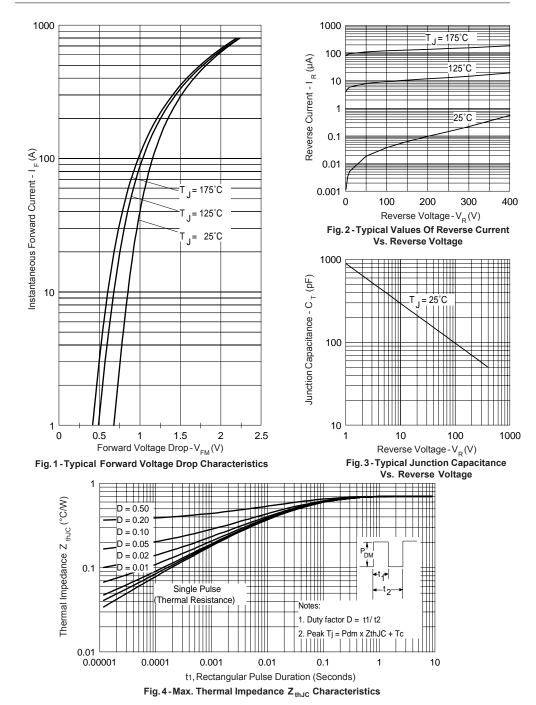
	Parameters	Min	Тур	Max	Units	Test Condition	t Conditions		
t _{rr}	Reverse Recovery Time	-	50	60	ns	$I_F = 1A$, $di_F/dt = 20$	0Α/μs, V _R = 30V		
		-	87	-		T _J = 25°C	I _F = 80A		
		-	151	-		T _J = 125°C	V _R = 200V di _F /dt = 200A/µs		
I _{RRM}	Peak Recovery Current	-	9.3	-	Α	T _J = 25°C	αι _Γ /αι – 200/4μ3		
		-	17.2	-		T _J = 125°C			
Q _{rr}	Reverse Recovery Charge	-	405	-	nC	T _J = 25°C			
			-	1300	-	T _J = 125°C			

Thermal - Mechanical Characteristics

	Parameters	Min	Тур	Max	Units
R _{thJC}	Thermal Resistance, Junction to Case			0.70	K/W
R _{thCS} ②	Thermal Resistance, Case to Heatsink		0.2		
Wt	Weight			5.02	g
			0.18		(oz)
Т	Mounting Torque	1.2		2.4	N * m
		10		20	lbf.in

② Mounting Surface, Flat, Smooth and Greased

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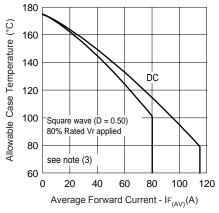


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

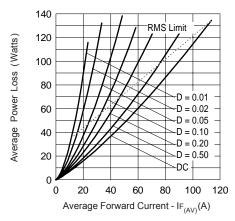


Fig. 6-Forward Power Loss Characteristics

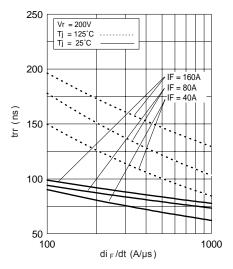


Fig. 7 - Typical Reverse Recovery time vs. di _F/dt

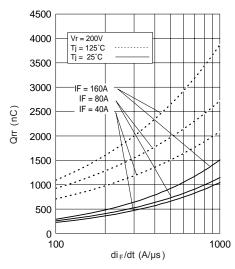


Fig. 8 - Typical Stored Charge vs. di $_{\text{F}}$ /dt

 $\begin{aligned} \textbf{(3)} \ \ &\text{Formula used:} \ T_{\text{C}} = T_{\text{J}} - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ &\text{Pd} = &\text{Forward Power Loss} = I_{F(\text{AV})} \times V_{\text{FM}} @ (I_{F(\text{AV})} / D) \ \ (\text{see Fig. 6}); \\ &\text{Pd}_{\text{REV}} = &\text{Inverse Power Loss} = V_{\text{R1}} \times I_{\text{R}} (1 - D); \ I_{\text{R}} @ V_{\text{R1}} = 80\% \ \text{rated} \ V_{\text{R}} \end{aligned}$

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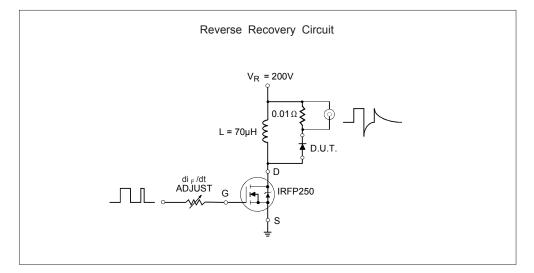


Fig. 9- Reverse Recovery Parameter Test Circuit

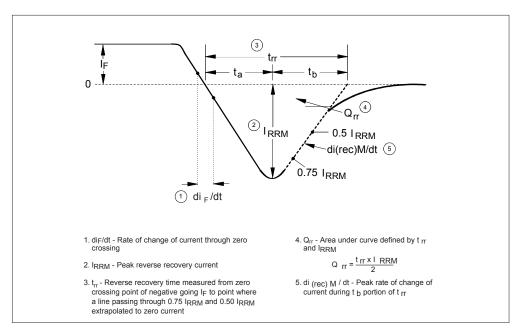
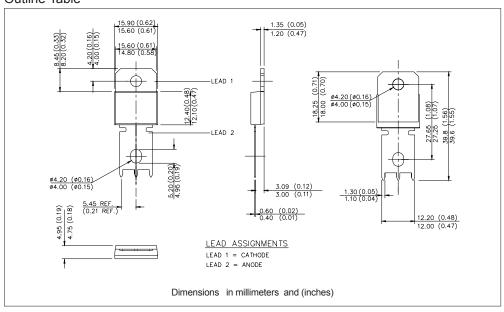


Fig. 10 - Reverse Recovery Waveform and Definitions

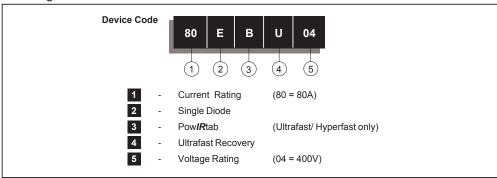
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Bulletin PD-20742 rev. C 02/06

Outline Table



Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free.

Qualification Standards can be found on IR's Web site.



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